

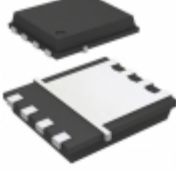
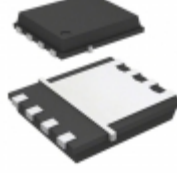
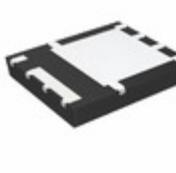
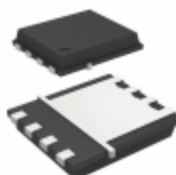
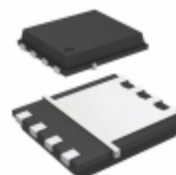

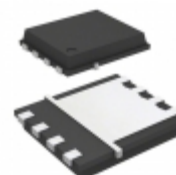
	<h2 style="color: red;">BSC009NE2LS</h2>	
	Hersteller-Teilenummer:	BSC009NE2LS
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	BSC009NE2LS Infineon Technologies
Datenblätter:	 BSC009NE2LS.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 9354 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	BSC009NE2LS
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	BSC009NE2LS Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	9354 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	PG-TDSON-8
Verlustleistung (max)	2.5W (Ta), 96W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	41A (Ta), 100A (Tc)
Rds On (Max) @ Id, Vgs	0.9 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	126nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5800pF @ 12V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

BSC009NE2LS ist neu im Original, Suche BSC009NE2LS Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie BSC009NE2LS International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage BSC009NE2LS: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>BSC010N04LS International Rectifier (Infineon Technologies) BSC010N04LS INFINEON</p>	 <p>BSC009NE2LS5ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 25V 41A 8TDFN</p>	 <p>BSC010N04LSIATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 37A 8TDFN</p>	 <p>BSC010N04LSTATMA1 International Rectifier (Infineon Technologies) DIFFERENTIATED MOSFETS</p>
 <p>BSC009NE2LSATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 25V 41A TDFN-8</p>	 <p>BSC009NE2LS5IATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 25V 40A 8TDFN IND</p>	 <p>BSC009NE2S INFINEON BSC009NE2S INFINEON</p>	 <p>BSC010N04LSATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 100A TDFN-8</p>

heiße Teile

Mehr

⊛ BSC009NE2S	↔ BSC010NE2LS	⇒ BSC010NE2LSI	D BSC011N03LS	⇒ BSC011N03NS3G
⊣ BSC014N03LS	⊛ BSC014N03LSG	D BSC014N03MSG	⇒ BSC014N03NS3G	⇒ BSC014NE2LSI
⊛ BSC014NE2LSIXT	⊣ BSC014NE2S	⊛ BSC016N03LS	↔ BSC016N03LSG	⇒ BSC016N03MSG
D BSC016N04LSG	⊛ BSC017N04NS3G	⊣ BSC017N04NSG	⊛ BSC018N04LSG	⇒ BSC018NE2LS
⇒ BSC018NE2LSI	↔ BSC018NE2SXT	⊛ BSC019N02KS	⊣ BSC019N02KSG	⇒ BSC019N02NS3G
↔ BSC019N04NS3G	⇒ BSC019N04NSGATMA1	D BSC020N025S	⊛ BSC020N025SG	⊣ BSC020N03LSG
⊛ BSC020N03MSG	D BSC020N03NS3G	⇒ BSC022N03S	↔ BSC022N03SG	⇒ BSC022N04LS
⊣ BSC022N04NS3G	⊛ BSC024N025SG	↔ BSC024NE2LS	⇒ BSC024NE2SXT	⇒ BSC025N03LSG
⊛ BSC025N03MS	⊣ BSC025N03MSG	⊛ BSC025N03NS3G	D BSC026N02NS3G	⇒ BSC026N04LS
↔ BSC026N08NS5	⊛ BSC026NE2LS5	⊣ BSC027N03SG	⊛ BSC027N04LSG	⇒ BSC027N04NS3G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited